SONY

Diagonal 6.0mm (Type 1/3) Progressive Scan CCD Image Sensor for Color Cameras



Description

The ICX445AQA is a diagonal 6.0mm (Type 1/3) interline CCD solid-state image sensor with a square pixel array and 1.25M effective pixels.

Progressive scan enables all pixel signals to be output separately within 1/22.5 second. The sensitivity and smear are improved drastically through the adoption of EXview HAD CCD technology.

Features

- Supports following modes All-pixel scan mode (15 frame/s, 12.5 frame/s, 22.5 frame/s: MAX) Center cut-out mode (30 frame/s, 25 frame/s)
- ◆ Horizontal drive frequency: 36.0MHz, 29.0MHz
- ◆ R, G, B primary color filters on chip
- + High resolution, high sensitivity, low dark current, low smear
- Excellent anti-blooming characteristics
- ♦ No voltage adjustments (Reset gate and substrate bias need no adjustment.)
- ◆ 24-pin high precision plastic package (Dual-surface reference available)

Package

24-pin DIP (Plastic)



* EXview HAD CCD is a trademark of Sony Corporation. The EXview HAD CCD is a CCD that drastically improves light efficiency by including near infrared light region as a basic structure of HAD (Hole-Accumulation Diode) sensor.

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Element Structure Interline CCD image sensor ♦ Image size Diagonal 6.0mm (Type 1/3) ◆ Total number of pixels 1348 (H) \times 976 (V) approx. 1.32M pixels Number of effective pixels 1296 (H) × 966 (V) approx. 1.25M pixels Number of active pixels 1280 (H) \times 960 (V) approx. 1.23M pixels ♦ Chip size 6.26mm (H) × 5.01mm (V) Unit cell size $3.75\mu m$ (H) imes $3.75\mu m$ (V) Optical black Horizontal (H) direction: Front 12 pixels, rear 40 pixels Front 8 pixels, rear 2 pixels Vertical (V) direction: Number of dummy bits Horizontal (H) direction: Front 4 pixels Vertical (V) direction: Front 2 pixels Substrate material Silicon

Optical Black Position

(Top View)



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Block Diagram and Pin Configuration



Pin Description

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	Vф2в	Vertical register transfer clock	13	Vout	Signal output
2	Vφ2Α	Vertical register transfer clock	14	GND	GND
3	Vфзв	Vertical register transfer clock	15	GND	GND
4	Vфза	Vertical register transfer clock	16	φRG	Reset gate clock
5	Vφ1Β	Vertical register transfer clock	17	LH¢1	Horizontal register final stage transfer clock
6	Vφ1Α	Vertical register transfer clock	18	Ηφ2Α	Horizontal register transfer clock
7	Vф4в	Vertical register transfer clock	19	Ηφ1Α	Horizontal register transfer clock
8	Vφ4A	Vertical register transfer clock	20	Нф1в	Horizontal register transfer clock
9	Vφsτ	Horizontal addition control clock	21	Нф2в	Horizontal register transfer clock
10	Vộhld	Horizontal addition control clock	22	φSUB	Substrate clock
11	VL	Protective transistor bias	23	NC	
12	NC		24	Vdd	Supply voltage

Absolute Maximum Ratings

	Item	Ratings	Unit	Remarks
	VDD, VOUT, $\phi RG - \phi SUB$	-39 to +12	V	
	Vφ2Α, Vφ2Β, Vφ3Α, Vφ3Β – φSUB	-46 to +17	V	
Against \$30B	Vφ1A, Vφ1B, Vφ4A, Vφ4B, VφST, VφHLD, VL – φSUB	-46 to +0.3	V	
	Hφ1a, Hφ1b, Hφ2a, Hφ2b, LHφ1, GND – φSUB	-39 to +0.3	V	
	VDD, VOUT, $\phi RG - GND$	-0.3 to +20	V	
Against GND	Vφ1a, Vφ1b, Vφ2a, Vφ2b, Vφ3a, Vφ3b, Vφ4a, Vφ4b, Vφst, Vφhld – GND	-9.0 to +17	V	
	Hφ1A, Hφ1B, Hφ2A, Hφ2B, LHφ1 – GND	-9.0 to +4.2	V	
	Vφ2A, Vφ2B, Vφ3A, V _φ 3B – VL	-0.3 to +25	V	
Against V∟	Vφ1a, Vφ1b, Vφ4a, Vφ4b, Vφst, Vφhld, Hφ1a, Hφ1b, Hφ2a, Hφ2b, LHφ1, GND – Vl	-0.3 to +13	V	
	Potential difference between vertical clock input pins	to +13	V	*1
Between input	Ηφ1Α, Ηφ1Β – Ηφ2Α, Ηφ2Β	-5 to +5	V	
	Ηφ1Α, Ηφ1Β, Ηφ2Α, Ηφ2Β – Vφ4Β, Vφhld	-13 to +13	V	
Storage temper	rature	-30 to +80	°C	
Operating temp	perature	-10 to +60	°C	

 *1 +25V (Max.) is guaranteed when clock width < 10 μs , clock duty factor < 0.1%.

Bias Conditions

Item	Symbol	Min.	Тур.	Max.	Unit	Remarks
Supply voltage	Vdd	14.55	15.0	15.45	V	
Protective transistor bias	VL		*1		V	
Substrate clock	φSUB		*2			
Reset gate clock	φRG		*2			

*1 VL setting is the VvL voltage of the vertical clock waveform, or the same voltage as the VL power supply for the V driver should be used.

^{*2} Do not apply a DC bias to the substrate clock and the reset gate clock pin, because a DC bias is generated internally.

DC Characteristics

Item	Symbol	Min.	Тур.	Max.	Unit	Remarks
Supply current	Idd		10.0		mA	

Clock Voltage Conditions

Item	Symbol	Min.	Тур.	Max.	Unit	Waveform diagram	Remarks
Readout clock voltage	Vvt	14.55	15.0	15.45	V	1	
	Vvh2, Vvh3	-0.05	0	0.05	V	2	Vvh = (Vvh2 + Vvh3)/2
	Vvh1, Vvh4, Vvhstr, Vvhhld	-0.2	0	0.05	v	2	
Vertical	Vvl1, Vvl2, Vvl3, Vvl4, Vvlstr, Vvlhld	-8.8	-8.5	-8.2	v	2	Vvl = (Vvl1 + Vvl4)/2
transfer clock voltage	νφν	8.0	8.5	8.85	V	2	$V\phi = V \vee Hn - V \vee Ln$ (<i>n</i> = 1 to 4)
	Vvh1 – Vvh	-0.25		0.1	V	2	
	Vvh4 – Vvh	-0.25		0.1	V	2	
	Vvнн			0.5	V	2	High-level coupling
	VVHL			0.5	V	2	High-level coupling
	VVLH			0.5	V	2	Low-level coupling
	VVLL			0.5	V	2	Low-level coupling
Horizontal	Vфн	3.4	3.6	3.8	V	3	
transfer clock	VHL	-0.05	0	0.05	V	3	
voltage	VCR	Vфн/2			V	3	Cross-point voltage
	Vørg	3.4	3.6	3.8	V	4	
Reset gate	Vrglh – Vrgll			0.4	V	4	Low-level coupling
electronage	VRGL – VRGLm			0.5	V	4	Low-level coupling
Substrate clock voltage	Vфsub	22.5	23.5	24.5	V	5	

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Clock Equivalent Circuit Constants

Item	Symbol	Min.	Тур.	Max.	Unit	Remarks
	Cφν1Α, Cφν1Β		1200		pF	
	Cφν2Α, Cφν2Β		2700		pF	
Capacitance between vertical transfer	Сфиза, Сфизв		680		pF	
	Cφν4Α, Cφν4Β		1800		pF	
	C∳Vst, C∳Vhld		1		pF	
	Cφν1αν2α, Cφν1βν2β		220		pF	
	Cφν1αν4b, Cφν1bν4a		47		pF	
Capacitance between vertical transfer	Cφν2αν3α, Cφν2βν3β		220		pF	
clocks	Cφν3αν4Α, Cφν3βν4β		390		pF	
	СфV3BVst, СфV4BVhld		47		pF	
	C∳V4BVst, C∳VstVhld		47		pF	
Capacitance between horizontal	Сфн1		32		pF	
transfer clock and GND	Сфн2		30		pF	
Capacitance between horizontal transfer clocks	Сфнн		56		pF	
Capacitance between reset gate clock and GND	C¢rg		1		pF	
Capacitance between substrate clock and GND	Сфѕив		330		pF	
Capacitance between horizontal final stage transfer clock and GND	Сф∟н1		1		pF	
Vertical transfer clock series resistor	RφV1A, RφV1B, RφV4A, RφV4B, RφVst, RφVhld		39		Ω	
	Rφv2a, Rφv2b, Rφv3a, Rφv3b		82		Ω	
Vertical transfer clock ground resistor	Rgnd		15		Ω	
Horizontal transfer clock series	Rфн1а, Rфн1в		18		Ω	
resistor	Rфн2а, Rфн2в		16		Ω	
Substrate clock series resistor	Rфsub		300		kΩ	

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Vertical transfer clock equivalent circuit



Horizontal transfer clock equivalent circuit

Drive Clock Waveform Conditions

1. Readout clock waveform



2. Vertical transfer clock waveform



 $V_{VH} = (V_{VH2} + V_{VH3})/2$ $V_{VL} = (V_{VL1} + V_{VL4})/2$ $V_{\varphi V} = V_{VH}n - V_{VL}n (n = 1 \text{ to } 4)$

3. Horizontal transfer clock waveform



Cross-point voltage for the H ϕ 1A, H ϕ 1B and LH ϕ 1 rising side of the horizontal transfer clocks H ϕ 1A, H ϕ 1B, LH ϕ 1 and H ϕ 2A, H ϕ 2B waveforms is VCR.

The overlap period for twh and twl of horizontal transfer clocks H\u00e91A, H\u00e91B, LH\u00e91 and H\u00e92A, H\u00e92B is "two".

4. Reset gate clock waveform



VRGLH is the maximum value and VRGLL is the minimum value of the coupling waveform during the period from Point A in the above diagram until the rising edge of RG.

In addition, $\mathsf{V}\mathsf{R}\mathsf{G}\mathsf{L}$ is the average value of $\mathsf{V}\mathsf{R}\mathsf{G}\mathsf{L}\mathsf{H}$ and $\mathsf{V}\mathsf{R}\mathsf{G}\mathsf{L}\mathsf{L}.$

VRGL = (VRGLH + VRGLL)/2

Assuming VRGH is the minimum value during the interval twh, then:

Vørg = Vrgh – Vrgl

Negative overshoot level during the falling edge of RG is VRGLm.

5. Substrate clock waveform



Clock Switching Characteristics

(Horizontal drive frequency: 36.0MHz)

ltem	Symbol		twh			twl			tr			tf		l Init	Pemarks
nem	Symbol	Min.	Тур.	Max.	Unit	Remarks									
Readout clock	VT	1.52	1.72						0.5			0.5		μS	During readout
Vertical transfer clock	Vφ1A, Vφ1B, Vφ2A, Vφ2B, Vφ3A, Vφ3B, Vφ4A, Vφ4B, Vφ5T, VφHLD										15		250	ns	When using CXD3400N
Horizontal	LHф1, Нф1А, Нф1в	8	9		8	9			5	6		5	6	ns	When driving at 3.6V during
	Нф2а, Нф2в	8	9		8	9			5	6		5	6		imaging, tf ≥ tr – 2ns
Reset gate clock	φRG	4	5.5			17.2			2			3		ns	
Substrate clock	φSUB	0.9	1.8							0.25			0.25	μs	When draining charge

Item	Symbol		two		Llnit	Pomarks	
nem	Symbol	Min.	Тур.	Max.	Onit	I CHIMINS	
Horizontal transfer clock	LHφ1, Hφ1A, Hφ1B, Hφ2A, Hφ2B	8	9		ns		

Spectral Sensitivity Characteristics

(excludes lens characteristics and light source characteristics)



Image Sensor Characteristics (Center cut-out drive, 30 frame/s)

(Ta =	25°C)
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Item		Symbol	Min.	Тур.	Max.	Unit	Measurement method	Remarks
G sensitivity		Sg	300	380		mV	1	1/30s accumulation
Sensitivity ratio	R	Rr	0.55		0.81		1	
Sensitivity ratio	В	Rb	0.23		0.49		1	
Saturation signal		Ysat	350			mV	2	Ta = 60°C
Smear		Sm		-104	-96	dB	3	
Video signal shadir	a	SHa			20	%	4	Zone 0 and I
video signal shading		Sily			25	%	4	Zone 0 to II'
Uniformity betweer	ı	∆Srg			8	%	5	
video signal chann	els	∆Sbg			8	%	5	
Dark signal		Vdt			2	mV	6	Ta = 60°C, 1/30s accumulation
Dark signal shading		∆Vdt			1	mV	7	Ta = 60°C, 1/30s accumulation ^{*1}
Line crawl R		Lcr			3.8	%	8	
Line crawl B		Lcb			3.8	%	8	
Lag		Lag			0.5	%	9	

*1 Excludes vertical dark signal shading caused by vertical register high-speed transfer.

Zone Definition of Video Signal Shading



Measurement System



Note) Adjust the amplifier gain so that the gain between [*A] and [*B], and between [*A] and [*C] equals 1.

Image Sensor Characteristics Measurement Method

Measurement conditions

- 1. In the following measurements, the device drive conditions are at the typical values of the bias and clock voltage conditions.
- 2. In the following measurements, spot pixels are excluded and, unless otherwise specified, the optical black level (OB) is used as the reference for the signal output, which is taken as the value of the Gr/Gb signal output or the R/B signal output of the measurement system.

Color coding of this image sensor & Readout

Gb	В	Gb	В	
R	Gr	R	Gr	
Gb	В	Gb	В	
R	Gr	R	Gr	
				Horizontal register

Color Coding Diagram

The primary color filters of this image sensor are arranged in the layout shown in the figure above (Bayer array). Gr and Gb denote the G signals on the same line as the R signal and the B signal, respectively.

The R signal and Gr signal lines and Gb signal and B signal lines are output successively.

Definition of standard imaging conditions

◆ Standard imaging condition I:

Use a pattern box (luminance : 706 cd/m², color temperature of 3200K halogen source) as a subject. (Pattern for evaluation is not applicable.) Use a testing standard lens with CM500S (t = 1.0mm) as an IR cut filter and image at F5.6. The luminous intensity to the sensor receiving surface at this point is defined as the standard sensitivity testing luminous intensity.

Standard imaging condition II:

Image a light source (color temperature of 3200K) with a uniformity of brightness within 2% at all angles. Use a testing standard lens with CM500S (t = 1.0mm) as an IR cut filter. The luminous intensity is adjusted to the value indicated in each testing item by the lens diaphragm.

1. G sensitivity, sensitivity ratio

Set to the standard imaging condition I. After setting the electronic shutter mode with a shutter speed of 1/100s, measure the signal outputs (VGr, VGb, VR and VB) at the center of each Gr, Gb, R and B channel screen, and substitute the values into the following formulas.

 $\label{eq:VG} \begin{array}{l} \mathsf{VG} = (\mathsf{VGr} + \mathsf{VGb})/2 \\ \mathsf{Sg} = \mathsf{VG} \times (100/30) \, [\mathsf{mV}] \\ \mathsf{Rr} = \mathsf{VR}/\mathsf{VG} \\ \mathsf{Rb} = \mathsf{VB}/\mathsf{VG} \end{array}$

2. Saturation signal

Set to the standard imaging condition II. After adjusting the luminous intensity to 20 times the intensity with the average value of the Gr signal output, 150mV, measure the minimum values of the Gr, Gb, R and B signal outputs.

3. Smear

Set to the standard imaging condition II. With the lens diaphragm at F5.6 to F8, first adjust the average value of the Gr signal output to 150mV. Measure the average values of the Gr signal output, Gb signal output, R signal output and B signal output (Gra, Gba, Ra, Ba), and then adjust the luminous intensity to 500 times the intensity with the average value of the Gr signal output, 150mV. After the readout clock is stopped and the charge drain is executed by the electronic shutter at the respective H blankings, measure the maximum value (VSm) independent of the Gr, Gb, R and B signal outputs, and substitute the values into the following formula.

Sm = $20 \times \log \{Vsm \div ((Gra + Gba + Ra + Ba)/4) \times (1/500) \times (1/10)\} [dB]$

4. Video signal shading

Set to the standard imaging condition II. With the lens diaphragm at F5.6 to F8, adjusting the luminous intensity so that the average value of the Gr signal output is 150mV. Then measure the maximum value (Grmax) and minimum value (Grmin) of the Gr signal and substitute the values into the following formula.

SHg = (Gmax – Gmin)/150 × 100 [%]

5. Uniformity between video signal channels

After the measurement item 4, measure the maximum (Rmax) and minimum (Rmin) values of the R signal and the maximum (Bmax) and minimum (Bmin) values of the B signal, and substitute the values into the following formula.

 $\label{eq:starsess} \begin{array}{l} \Delta Srg = (Rmax - Rmin)/150 \times 100 \ [\%] \\ \Delta Sbg = (Bmax - Bmin)/150 \times 100 \ [\%] \end{array}$

6. Dark signal

Measure the average value of the signal output (Vdt) with the device ambient temperature of 60°C and the device in the light-obstructed state, using the horizontal idle transfer level as a reference.

7. Dark signal shading

After the measurement item 6, measure the maximum (Vdmax) and minimum (Vdmin) values of the dark signal output and substitute the values into the following formula.

 Δ Vdt = Vdmax – Vdmin [mV]

8. Line crawl

Set to the standard imaging condition II. Adjusting the luminous intensity so that the average value of the Gr signal output is 150mV, and then insert R, G and B filters and measure the difference between G signal lines (Δ Glr, Δ Glg, Δ Glb) as well as the average value of the G signal output (Gar, Gag, Gab). Substitute the values into the following formula.

$$Lci = (\Delta Gli/Gai) \times 100 [\%] (i = r, g, b)$$

9. Lag

Adjust the Gr signal output value generated by strobe light to 150mV. After setting the strobe light so that it strobes with the following timing, measure the residual signal (Vlag). Substitute the value into the following formula.



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Drive Circuit



Drive Timing Chart

All-pixel Scan Mode (15 frame/s) Vertical Direction



All-pixel Scan Mode (12.5 frame/s) Vertical Direction



All-pixel Scan Mode (22.5 frame/s) Vertical Direction

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Center Cut-out Mode (30 frame/s) V	ertical Direction
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TGVD	Fractional adjustment line	
SUB		
V1		
V2B		
High-speed sv	weep Frame shift	,
8H + α (178 \$	steps): $11H + \alpha$ (129 steps) 11H + α (129 steps)	
V3A T		
V3B		
V4		
VSTR		
АНГР		
CCD OUT		<u>∠t8</u>
PBLK		
CLPOB		
CLPDM		



Center Cut-out Mode (25 frame/s) Vertical Direction

TGVD 745 (0) 12 12 12 12 12 12 12 12 12 12 12 12 12		745 (0)
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V1		
High-speed sweep		7
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The TGVD in this chart is noted at 744H (1H: 1556 clocks) + 1H (2336 clocks: fractional adjustment line). (1 clock = 29.0MHz)

All-pixel Scan Mode (15 frame/s, 12.5 frame/s) Horizontal Direction High-speed sweep block [A]





The numbers at the output pulse transition points indicate the count at the rising edge of the clock from the falling edge of TGHD. The numbers on the upper level are for 36.0 MHz, and the numbers in parentheses on the lower are for 29.0 MHz.

Center cut-out Mode (30 frame/s, 25 frame/s) Horizontal Direction High-speed sweep block [A]





The numbers at the output pulse transition points indicate the count at the rising edge of the clock from the falling edge of TGHD. The numbers on the upper level are for 36.0 MHz, and the numbers in parentheses on the lower are for 29.0 MHz.

All-pixel Scan Mode (15 frame/s, 12.5 frame/s, 22.5 frame/s)/Center Cut-out Mode (30 frame/s, 25 frame/s) Horizontal Direction Normal Transfer Block [B]



All-pixel Scan Mode (15 frame/s, 12.5 frame/s, 22.5 frame/s)/ Center Cut-out Mode (30 frame/s, 25 frame/s) Horizontal Direction Readout Block [C]





Center Cut-out Mode (30 frame/s, 25 frame/s) Horizontal Direction Frame Shift Block [D]



SUB pulse generation is prohibited during the frame shift period.

The numbers at the output pulse transition points indicate the count at the rising edge of the clock from the falling edge of TGHD. The numbers on the upper level are for 36.0 MHz, and the numbers in parentheses on the lower are for 29.0 MHz.

Notes On Handling

1. Static charge prevention

CCD image sensors are easily damaged by static discharge. Before handling be sure to take the following protective measures.

- (1) Either handle bare handed or use non-chargeable gloves, clothes or material. Also use conductive shoes.
- (2) Use a wrist strap when handling directly.
- (3) Install grounded conductive mats on the floor and working table to prevent the generation of static electricity.
- (4) Ionized air is recommended for discharge when handling CCD image sensors.
- (5) For the shipment of mounted boards, use boxes treated for the prevention of static charges.

2. Soldering

- (1) Make sure the package temperature does not exceed 80°C.
- (2) Solder dipping in a mounting furnace causes damage to the glass and other defects. Use a 30W soldering iron with a ground wire and solder each pin in 2 seconds or less. For repairs and remount, cool sufficiently.
- (3) To dismount an image sensor, do not use solder suction equipment. When using an electric desoldering tool, use a thermal controller of the zero-cross On/Off type and connect it to ground.
- 3. Protection from dust and dirt

Image sensors are packed and delivered with care taken to protect the element glass surfaces from harmful dust and dirt. Clean glass surfaces with the following operations as required before use.

- (1) Perform all lens assembly and other work in a clean room (class 1000 or less).
- (2) Do not touch the glass surface with hand and make any object contact with it. If dust or other is stuck to a glass surface, blow it off with an air blower. (For dust stuck through static electricity, ionized air is recommended.)
- (3) Clean with a cotton bud and ethyl alcohol if grease stained. Be careful not to scratch the glass.
- (4) Keep in a dedicated case to protect from dust and dirt. To prevent dew condensation, preheat or precool when moving to a room with great temperature differences.
- (5) When a protective tape is applied before shipping, remove the tape applied for electrostatic protection just before use. Do not reuse the tape.
- 4. Installing (attaching)
 - (1) Remain within the following limits when applying a static load to the package. Do not apply any load more than 0.7mm inside the outer perimeter of the glass portion, and do not apply any load or impact to limited portions. (This may cause cracks in the package.)



Compressive strength

Torsional strength

- (2) If a load is applied to the entire surface by a hard component, bending stress may be generated and the package may fracture, etc., depending on the flatness of the bottom of the package. Therefore, for installation, use either an elastic load, such as a spring plate, or an adhesive.
- (3) The adhesive may cause the marking on the rear surface to disappear, especially in case the regulated voltage value is indicated on the rear surface. Therefore, the adhesive should not be applied to this area, and indicated values should be transferred to the other locations as a precaution.

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- (4) The notch of the package is used for directional index, and that can not be used for reference of fixing. In addition, the cover glass and seal resin may overlap with the notch of the package.
- (5) If the lead bend repeatedly and the metal, etc., clash or rub against the package, dust may be generated by the fragments of resin.
- (6) Acrylate anaerobic adhesives are generally used to attach CCD image sensors. In addition, cyanoacrylate instantaneous adhesives are sometimes used jointly with acrylate anaerobic adhesives. (reference)
- 5. Others
 - (1) Do not expose to strong light (sun rays) for long periods, as color filters will be discolored. When high luminous objects are imaged with the exposure level controlled by the electronic iris, the luminance of the image-plane may become excessive and discoloration of the color filters may be accelerated. In such a case, arrangements such as using an automatic iris with the imaging lens or automatically closing the shutter during power-off are advisable. For continuous use under harsh conditions exceeding the normal conditions of use, consult your Sony representative.
 - (2) Exposure to high temperature or humidity will affect the characteristics. Accordingly avoid storage or usage in such conditions.
 - (3) Brown stains may be seen on the bottom or side of the package. But this does not affect the CCD characteristics.

